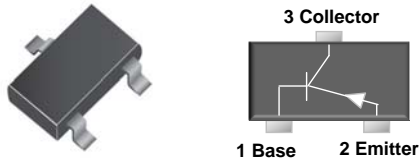


Small Signal Diode

SOT-23

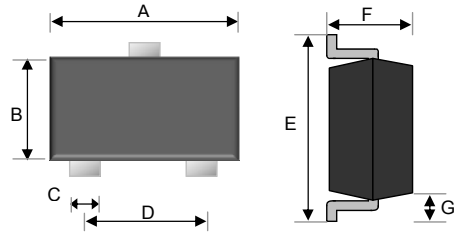


Features

- ✧ Epitaxial planar die construction
- ✧ Surface device type mounting
- ✧ Moisture sensitivity level 1
- ✧ Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- ✧ Pb free version and RoHS compliant
- ✧ Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

Mechanical Data

- ✧ Case : SOT- 23 small outline plastic package
- ✧ Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ High temperature soldering guaranteed: 260°C/10s
- ✧ Weight : 0.008gram (approximately)
- ✧ Marking Code : 2A

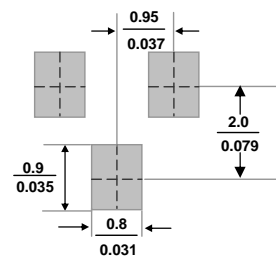


Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	2.80	3.00	0.110	0.118
B	1.20	1.40	0.047	0.055
C	0.30	0.50	0.012	0.020
D	1.80	2.00	0.071	0.079
E	2.25	2.55	0.089	0.100
F	0.90	1.20	0.035	0.043
G	0.550 REF		0.022 REF	

Ordering Information

Package	Part No.	Packing	Marking
SOT-23	MMBT3906 RF	3K / 7" Reel	2A
SOT-23	MMBT3906 RFG	3K / 7" Reel	2A

Suggested PAD Layout



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P_D	300	mW
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to + 150	°C

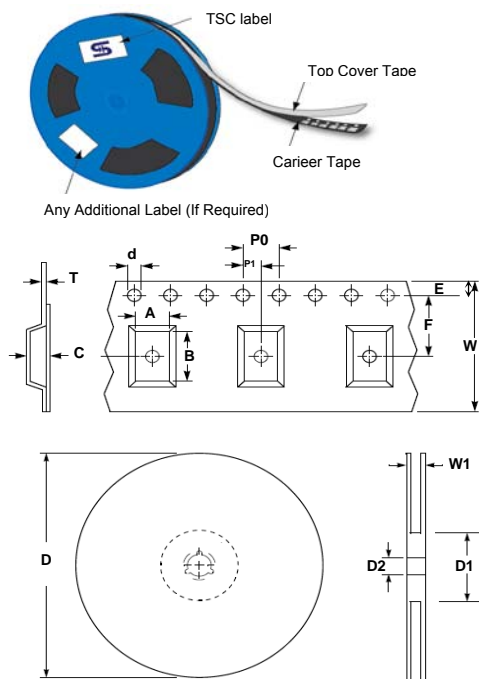
Notes:1. Valid provided that electrodes are kept at ambient temperature

Small Signal Diode

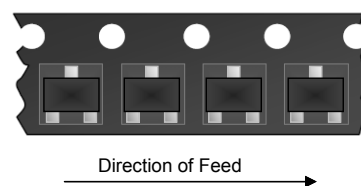
Electrical Characteristics

Type Number			Symbol	Min	Max	Units
Collector-Base Breakdown Voltage	$I_C = -10\mu A$	$I_E = 0$	$V_{(BR)CBO}$	-40	-	V
Collector-Emitter Breakdown Voltage	$I_C = -1mA$	$I_B = 0$	$V_{(BR)CEO}$	-40	-	V
Emitter-Base Breakdown Voltage	$I_E = -10\mu A$	$I_C = 0$	$V_{(BR)EBO}$	-5	-	V
Collector Cut-off Current	$V_{CB} = -40V$	$I_E = 0$	I_{CBO}	-	-0.1	μA
Collector Cut-off Current	$V_{CE} = -30V$	$V_{BE(OFF)} = -3V$	I_{CEX}	-	-50	nA
Emitter Cut-off Current	$V_{EB} = -5V$	$I_C = 0$	I_{EBO}	-	-0.1	μA
DC current gain	$V_{CE} = -1V$	$I_C = -10mA$	h_{FE}	100	300	
	$V_{CE} = -1V$	$I_C = -50mA$		60	-	
	$V_{CE} = -1V$	$I_C = -100mA$		30	-	
Collector-Emitter saturation voltage	$I_C = -50mA$	$I_B = -5mA$	$V_{CE(sat)}$	-	-0.4	V
Base-Emitter saturation voltage	$I_C = -50mA$	$I_B = -5mA$	$V_{BE(sat)}$	-	-0.95	V
Transition frequency	$V_{CE} = -20V$	$I_C = -10mA$	f_T	250	-	MHz
Delay time	$V_{CC} = -3V$	$V_{BE} = -0.5V$	t_d	-	35	nS
Rise time		$I_{B1} = -1.0mA$	t_r	-	35	nS
Storage time	$V_{CC} = -3V$	$I_C = -10mA$	t_s	-	225	nS
Fall time		$I_{B1} = I_{B2} = -1.0mA$	t_f	-	75	nS

Tape & Reel specification



Item	Symbol	Dimension(mm)
Carrier width	A	3.15 ±0.10
Carrier length	B	2.77 ±0.10
Carrier depth	C	1.22 ±0.10
Sprocket hole	d	1.50 ± 0.10
Reel outside diameter	D	178 ± 1
Reel inner diameter	D1	55 Min
Feed hole width	D2	13.0 ± 0.20
Sprocket hole position	E	1.75 ±0.10
Punch hole position	F	3.50 ±0.05
Sprocket hole pitch	P0	4.00 ±0.10
Embossment center	P1	2.00 ±0.05
Overall tape thickness	T	0.229 ±0.013
Tape width	W	8.10 ±0.20
Reel width	W1	12.30 ±0.20



Small Signal Diode

Rating and Sharacteristic Curves

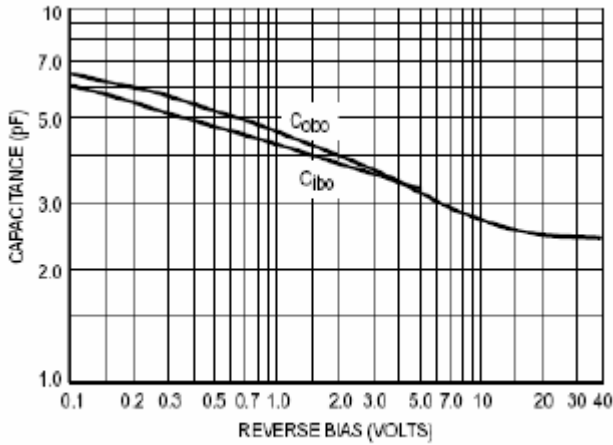


Figure 1 Capacitance

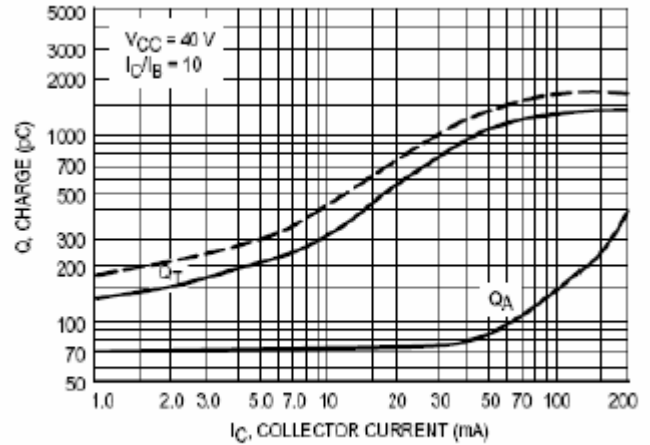


Figure 2 Charge Data

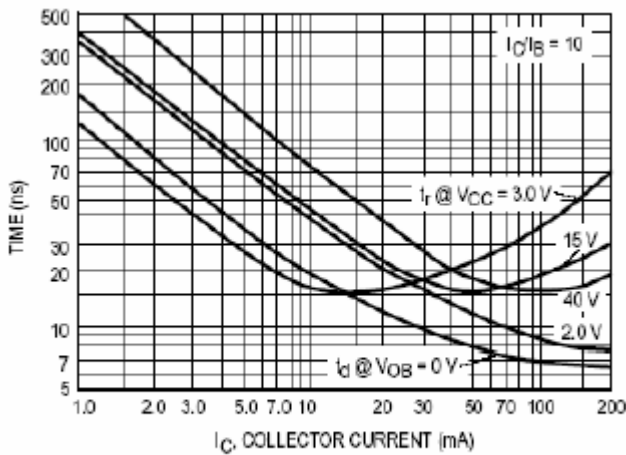


Figure 3 Turn-On Time

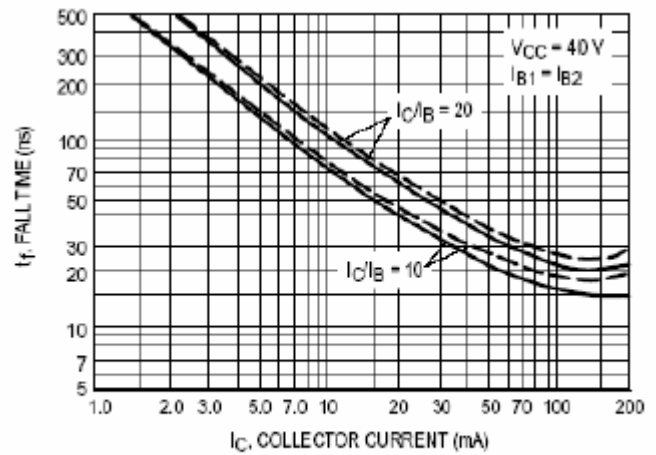


Figure 4 Fall Time

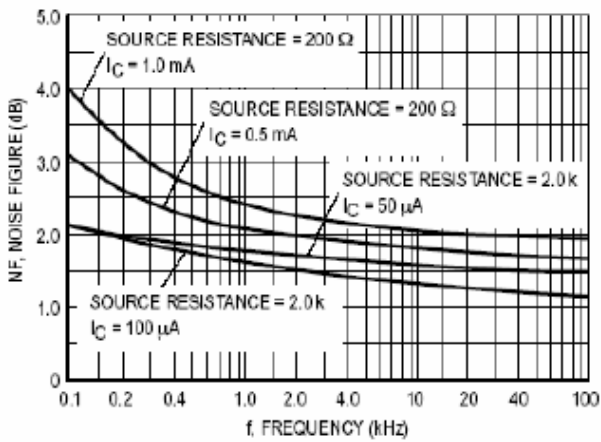


Figure 5

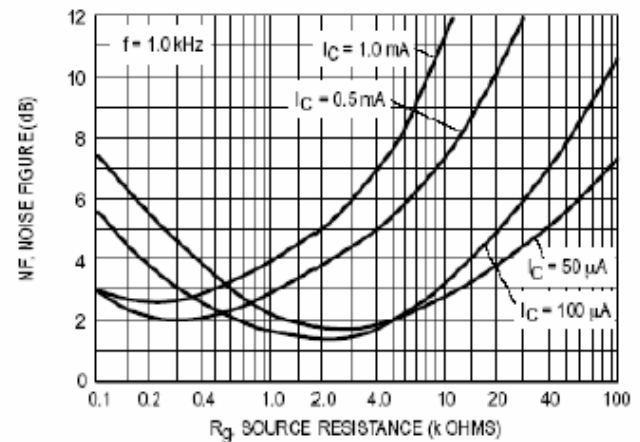


Figure 6

Small Signal Diode

Rating and Sharacteristic Curves

h PARAMETERS

($V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$, $T_A = 25^\circ\text{C}$)

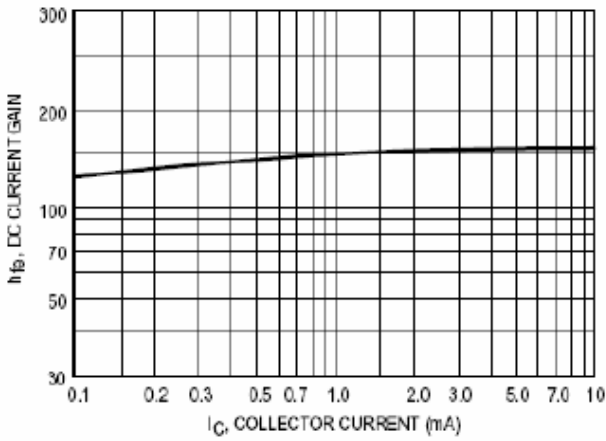


Figure 7 Current Gain

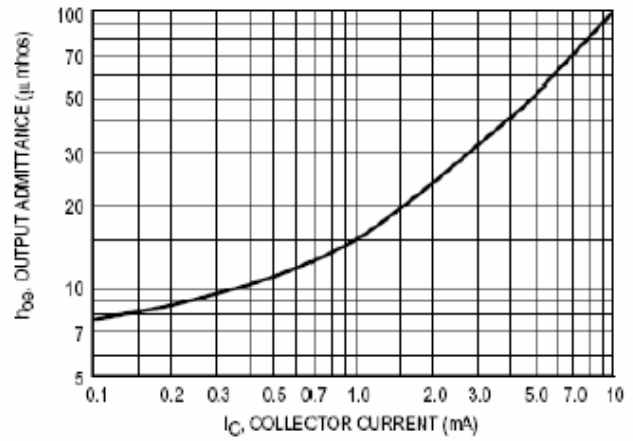


Figure 8 Output Admittance

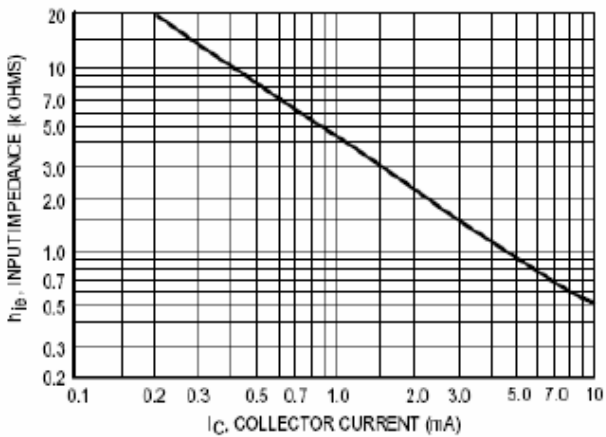


Figure 9 Input Impedance

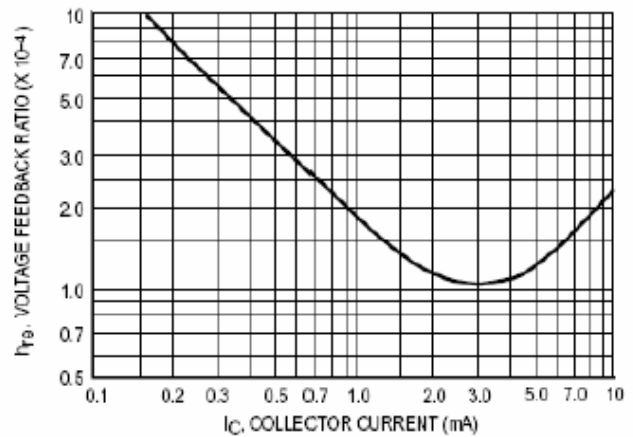


Figure 10 Voltage Feedback Ratio

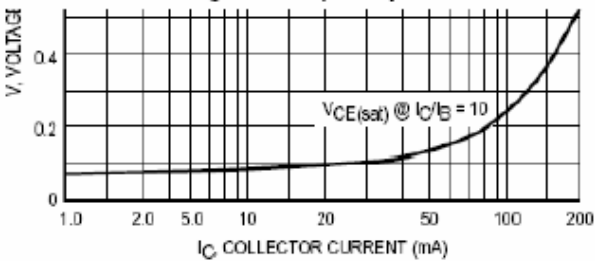


Figure 11 "ON" Voltages

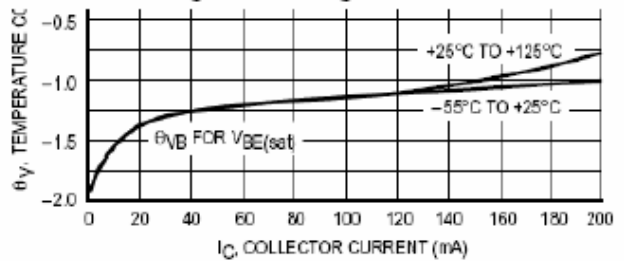


Figure 12 Temperature Coefficients